

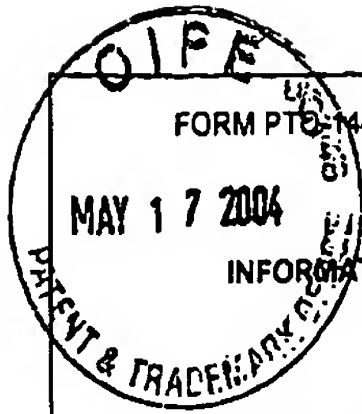
FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY)	ATTY. DOCKET NO. MICRON.098CDV2	APPLICATION NO. Unknown 18/615,524
	APPLICANT Basceri et al.	
	FILING DATE Herewith 3 JUL 03	GROUP Unknown 2823

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
QNB	1	5,335,138	8/2/94	Sandhu et al.	361	383	A
QNB	2	5,406,445	4/11/95	Fujii et al.	361	385	
QNB	3	5,506,166	4/9/96	Sandhu et al.	438	390	
QNB	4	5,717,234	2/10/98	Si et al.	257	295	
QNB	5	5,781,404	7/14/98	Summerfelt et al.	361	321.5	
QNB	6	5,783,253	7/21/98	Roh	427	81	
QNB	7	5,889,299	3/30/99	Abe et al.	257	295	
QNB	8	5,973,911	10/26/99	Nishioka	361	313	
QNB	9	6,010,931	1/4/00	Sun et al.	438	48	
QNB	10	6,117,482	9/12/00	Kawahara et al.	427	18	
QNB	11	6,136,639	10/24/00	Seon	438	238	
QNB	12	6,319,764 B1	11/20/01	Basceri et al.	438	240	J

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)	
QNB	13	Hiromi Itoh et al., "Integration of BST Thin Film for Dram Fabrication", Integrated Ferroelectrics, 1995 Vol. 11, pp.101-109
QNB	14	C. Basceri, "An Important Failure Mechanism in MOCVD (Ba,Sr)TiO ₃ Thin Films: Resistance Degradation", Ferroelectric Thin Films IV, Materials Research Society, Symposium Proceedings Volume 493, 1998, pp. 9-14
QNB	15	Chung Ming Chu and Pang Lin, "Electric Properties and Crystal Structure of a (Ba,Sr)TiO ₃ Films Prepared at Low Temperatures on a LaNiO ₃ Electrode by Radio-Frequency Magnetron Sputtering", Appl. Phys. Lett., Vol. 70 (2), 13 January 1997, pp.249-51
	16	
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EXAMINER	William M. Brumter	DATE CONSIDERED	14 APR 03
*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.			



FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.
MICRON.098CDV2APPLICATION NO.
10/615,524INFORMATION DISCLOSURE STATEMENT
BY APPLICANT

(USE SEVERAL SHEETS IF NECESSARY)

APPLICANT
Basceri et al.FILING DATE
July 3, 2003GROUP
2823

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
QVB	1.	6,285,051	09/04/01	Ueda et al.	257	296	A

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)	

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EXAMINER <i>William M. Brewster</i>	DATE CONSIDERED <i>14 APR 05</i>
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Multiple sheets used when necessary) SHEET 1 OF 1	Application No.	10/615,524
	Filing Date	July 3, 2003
	First Named Inventor	Basceri et al.
	Art Unit	2823
	Examiner	William M. Brewster
Attorney Docket No.		MICRON.098CDV2

PATENT DOCUMENTS					
Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
W/B	1.	6,852,593	02/08/05	Basceri et al. 438/253	X
W/B	2.	6,855,971	02/15/05	Basceri et al. 257/298	X

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No.	Foreign Patent Document Country Code-Number-Kind Code Example: JP 1234567 A1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T ¹
W/B	3.	EPO 0 617 439 A2	03-24-1994	Matsushita Electric Industrial Co.	X	X
W/B	4.	JP 406 333 772A	12-02-1994	Fujii et al.	X	X

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
W/B	5.	Copy of Claims as allowed in Amendment filed August 14, 2004 in Application No. 10/614,418, filed July 3, 2003	X
W/B	6.	Copy of March 14, 2003 Office Action in U.S. Patent No. 6,855,971 causing JP 406 333 772A to be listed.	X

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Examiner Signature <i>William M. Brewster</i>	Date Considered <i>14 APR 05</i>
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

T¹ - Place a check mark in this area when an English language Translation is attached.